PPM 92-116

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Interoffice Memorandum

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Department

Code 311

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Radiation Report on CD54HC4053F3A GGS/WIND/WAVES Control No. 5733

Date PPM-92-116

LocaliMarch 20, 1992

TelephG SFC

Location 31-8954

_ Lanham

E. Werner/406

M. Kaiser/695

G. Robinson/303

A. Sharma/311

Library/300.1

A radiation evaluation was performed on CD54HC4053F3A to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Tables I through IV and Figure 1.

The total dose testing was performed using a cobalt-60 gamma ray source. During the radiation testing, four parts were irradiated under bias (see Figure 1 for bias configuration), and one part was used as a control sample. The total dose radiation steps were 5, 10, 15 and 20 krads (In this report, the term rad means rad (Si)). After 20 krads, parts were annealed at +25°C for 168 hours and then at +100°C for 168 hours. The dose rate was between 0.05 and 0.12 krads/hour, depending on the total dose level (see Table II for radiation schedule). After each radiation exposure and annealing treatment, parts were electrically tested according to the test conditions and the specification limits listed in Table III. These tests included six functional tests (1 MHz) at 2.0, 4.5 and 6.0V.

All four irradiated parts exceeded the maximum specification limits for IIZON2, ICCH and ICCL after the first radiation exposure to 5 krads. The readings for IIZON2 were in the range of 1000 - 4000 nA, against the maximum specification limit of 100 The ICCH readings ranged from 30 - 40 uA against a maximum specification limit of 16 uA, while the ICCL readings ranged from 18 - 20 uA against a maximum specification limit of 8 uA. After 10 krads exposure, parts showed increasing degradation for all of these parameters. Additionally, all four parts exceeded maximum specification limits for IIZON1, IIZOFF1 and IIZOFF2 after 10 krads exposure. All parts continued to show increasing degradation for all six parameters at 15 and 20 krads exposure. Also, all parts failed functional test #4 after 15 krads exposure and functional tests #'s 4, 5 and 6 after 20 krads exposure. No significant recovery occurred after annealing for 168 hours at 25°C and 1268 hours at 100°C.

Table IV provides a summary of the functional test results, as well as the mean and standard deviation values for each parameter after different irradiation exposures and annealing steps. Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at (301) 731-8954.

2011) 45 (0.186)

TABLE I. Part Information

Generic Part Number:

54HC4053

GGS/WIND/WAVES

Part Number:

CD54HC4053F3A

GGS/WIND/WAVES

Control Number:

5733

Charge Number:

C23418

Manufacturer:

RCA

Lot Date Code:

8805B

Quantity Tested:

5

Serial Numbers of

Radiation Samples:

84, 85, 86, 87

Serial Numbers of

Control Sample:

83

Part Function:

multiplexer/demultiplexer

Part Technology:

CMOS

Package Style:

16-lead DIP

Test Engineer:

Ted Scharer

TABLE II. Radiation Schedule for 54HC4053

EVENTS	DATE
1) Initial Electrical Measurements	02/03/92
2) 5 KRAD IRRADIATION (0.12 krads/hour) POST-5 KRAD ELECTRICAL MEASUREMENT	02/03/92 02/05/92
3) 10 KRAD IRRADIATION (0.12 krads/hour) POST-10 KRAD ELECTRICAL MEASUREMENT*	02/05/92 02/12/92
4) 15 KRAD IRRADIATION (0.12 krads/hour) POST-15 KRAD ELECTRICAL MEASUREMENT	02/12/92 02/14/92
5) 20 KRAD IRRADIATION (0.05 KRADS/HOUR) POST-20 KRAD ELECTRICAL MEASUREMENT	02/14/92 02/18/92
6) 168 HOUR ANNEALING @ 25°C POST-168 HOUR 25°C ANNEAL ELECTRICAL MEASUREMENT	02/18/92 03/03/92
7) 168 HOUR ANNEALING @ 100°C POST-168 HOUR 100°C ANNEAL ELECTRICAL MEASUREMENT	03/03/92 03/10/92

*Testing was delayed five days due to down time on automatic test equipment. Parts were annealed at 25°C while delayed.

all electrical measurements performed at 25°C.

All parts irradiated under bias, see Figure 1.

All annealings performed under bias, see Figure 1.

Table III. Electrical Characteristics of 54HC4053

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TABLE IV: Summary of Electrical Measurements After Total Dose Exposures and Annealing Steps for 54HC4053 1/

				<u> </u>	Total Dose Exposure (TDE) (krads)									Annea	1	Anneal				
					To	5	se ba	10		1.5		20		168 F		168 I 6+10				
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UNC4				P		P		P		2.		F		F		3P/1F				
UNC5				200		P		P		£			N/A	0	N/A	0	N/A			
UNC6	— 	-100	100	0	N/A	0	N/A	0	N/A	C.	N/A	0	N/A	0	N/A	10	N/A			
I IH	<u>nA</u>		100	0	N/A	0	N/A	0	N/A	0	N/A	0		62,64	7.2	62.18				
IIL	πA	-10 0	180	64.72	8.2	65.10	8.7	61,75	6.9	61.78		60.48	7.9	52.64		52.15				
R ON 1	emrio	0	160	51.76	6.9	52.19	7.1	51.78	6.9	50,95		50.08				2.5E4				
RON_2	emdo	0		6	N/A	5.54	11	2315	2374	1,824	·		_	3.2E4	_	-3E4	2.4E			
IIZON1	n.A.	-100	100	0	N/A	1965	2040	-184	9464	-324		200000000000000000000000000000000000000	3.5E4		3E4	2.1E4				
IIZON2	nA	-100	100	Ö	N/A	9.50	13	1930	1942	1,256		2,984		2.6B4						
IIZOFF1	nΑ	-100	100	0	N/A	0	N/A	-1877	2032	-926	9593			-1E4		-9650	·			
IIZOFF2	nA		100		N/A	37.46	3.3	289	30	969	89	1926	248	1645	217	1261	— —			
ICCH	υA		16	0	N/A	19.66		189	13	737	67	1556	252	1334	219	1028	107			
ICCL	uA	0	8	0	N/A			50-2-10-20-22-22		45555		•-								

The control sample remained constant throughout the testing and is not included in this table.

^{1/} The mean and standard deviation values were calculated over the four parts irradiated in this

Figure 1. Radiation Bias Circuit for 54HC4053

